

## Features

- Meets MIL-S-19500/366
- Collector-Base Voltage 150V
- Collector Current: 500 mA
- Fast Switching 1265 nS

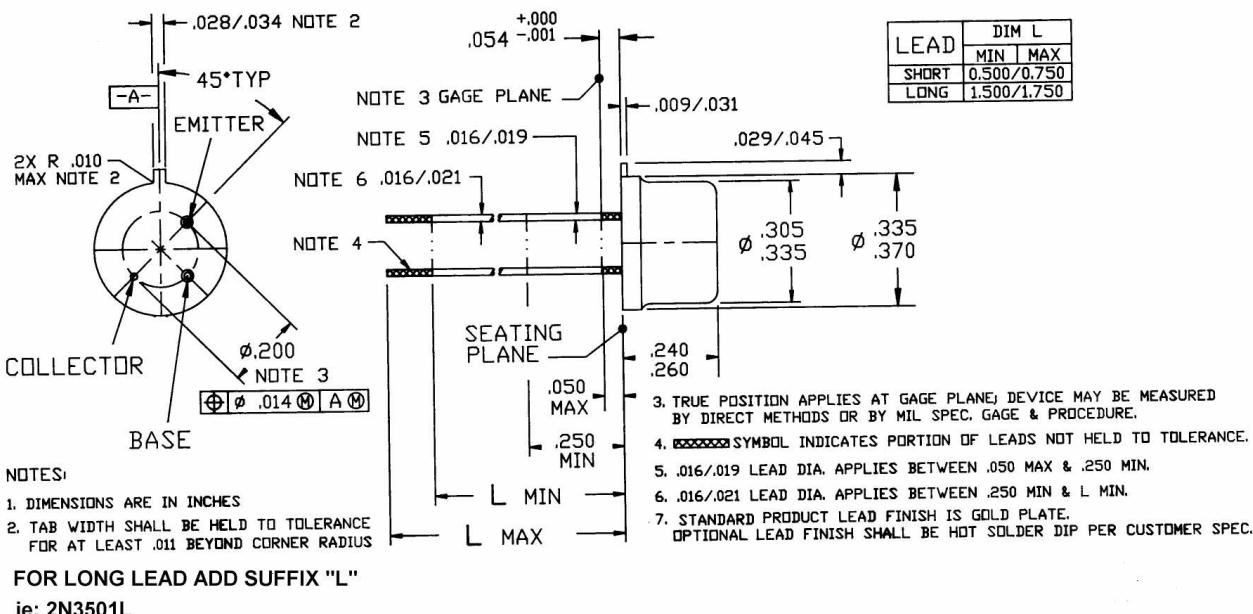
**150 Volts  
 500mAmps**

**NPN  
 BIPOLEAR  
 TRANSISTOR**

## Maximum Ratings

RATING	SYMBOL	MAX.	UNIT
Collector-Emitter Voltage	$V_{CEO}$	150	Vdc
Collector-Base Voltage	$V_{CBO}$	150	Vdc
Emitter-Base Voltage	$V_{EBO}$	6.0	Vdc
Collector Current—Continuous	$I_C$	300	mAdc
Total Device Dissipation $\text{ @ } T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.0 5.71	Watt $\text{mW}/^\circ\text{C}$
Total Device Dissipation $\text{ @ } T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	5.0 28.6	Watts $\text{mW}/^\circ\text{C}$
Operating Temperature Range	$T_J$	-55 to +200	$^\circ\text{C}$
Storage Temperature Range	$T_S$	-55 to +200	$^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	175	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	35	$^\circ\text{C}/\text{W}$

## Mechanical Outline



2N3501

## Electrical Parameters ( $T_A @ 25^\circ C$ unless otherwise specified)

CHARACTERISTICS	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>Off Characteristics</b>					
Collector-Emitter Breakdown Voltage(1) ( $I_C = 10 \text{ mA}_\text{dc}$ , $I_B = 0$ )	$\text{BV}_{\text{CEO}}$	150	--	--	Vdc
Collector-Base Breakdown Voltage ( $I_C = 10 \mu\text{A}_\text{dc}$ , $I_E = 0$ )	$\text{BV}_{\text{CBO}}$	150	--	--	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \mu\text{A}_\text{dc}$ , $I_C = 0$ )	$\text{BV}_{\text{EBO}}$	6.0	--	--	Vdc
Collector Cutoff Current ( $V_{CB} = 75 \text{ Vdc}$ , $I_E = 0$ ) ( $V_{CB} = 75 \text{ Vdc}$ , $I_E = 0$ , $T_A = 150^\circ \text{C}$ )	$I_{\text{CBO}}$	-- --	-- --	0.05 50	$\mu\text{A}_\text{dc}$
Emitter Cutoff Current ( $V_{EB(\text{off})} = 4.0 \text{ Vdc}$ , $I_C = 0$ )	$I_{\text{EBO}}$	--	--	25	nAdc
D.C. Current Gain ( $I_C = 0.1 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ Vdc}$ ) ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ Vdc}$ ) ( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ Vdc}$ )(1) ( $I_C = 150 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ Vdc}$ )(1) ( $I_C = 150 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ Vdc}$ ) @ 55C ( $I_C = 300 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ Vdc}$ )(1)	$h_{\text{FE}}$	35 50 75 100 45 20	-- -- -- -- -- --	-- -- -- 300	--
Collector-Emitter Saturation Voltage(1) ( $I_C = 10 \text{ mA}_\text{dc}$ , $I_B = 1.0 \text{ mA}_\text{dc}$ ) ( $I_C = 150 \text{ mA}_\text{dc}$ , $I_B = 15 \text{ mA}_\text{dc}$ )	$V_{CE(\text{Sat})}$	-- --	-- --	0.2 0.4	Vdc
Base-Emitter Saturation Voltage(1) ( $I_C = 10 \text{ mA}_\text{dc}$ , $I_B = 1.0 \text{ mA}_\text{dc}$ ) ( $I_C = 150 \text{ mA}_\text{dc}$ , $I_B = 15 \text{ mA}_\text{dc}$ )	$V_{BE(\text{Sat})}$	-- --	-- --	0.8 1.2	Vdc
Magnitude of common emitter small-signal short-circuit forward current transfer ratio ( $V_{CE} = 20 \text{ Vdc}$ , $I_C = 20 \text{ mA}_\text{dc}$ , $f = 100 \text{ MHz}$ )	$ h_{fe} $	1.5	--	8	
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $100\text{kHz} < f \leq 1\text{MHz}$ )	$C_{\text{OBO}}$	--	--	8.0	pf
Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_C = 0$ , $100\text{kHz} < f \leq 100\text{MHz}$ )	$C_{\text{IBO}}$	--	--	80	pf
Small -signal Current Gain ( $I_C = 10\text{mA}_\text{dc}$ , $V_{CE} = 10\text{Vdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{\text{fe}}$	75	--	300	
Noise figure ( $V_{CE} = 10\text{Vdc}$ , $I_C = 0.5\text{mA}_\text{dc}$ ; $R_g = 1\text{kohms}$ , $f = 1\text{MHz}$ )	$NF$			16	dB
Noise figure ( $V_{CE} = 10\text{Vdc}$ , $I_C = 0.5\text{mA}_\text{dc}$ ; $R_g = 1\text{kohms}$ , $f = 1\text{MHz}$ )	$NF$			6	dB
Turn - on time ( $V_{EB} = 12\text{Vdc}$ , $I_C = 150\text{mA}_\text{dc}$ , $I_{B1} = 15\text{mA}_\text{dc}$ )	$t_{\text{on}}$			115	nS
Turn - off time ( $I_C = 150\text{mA}_\text{dc}$ , $I_{B1} = I_{B2} = -15\text{mA}_\text{dc}$ )	$t_{\text{off}}$			1150	nS

(1) Pulse Test: Pulse Width  $\leq 300 \text{ ms}$ , Duty Cycle  $\leq 2.0\%$